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Product: SMD1206P016TF

Revision: H

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Device Specification

ELECTRICAL CHARACTERISTICS





Part Number						Maximum Time To Trip		Resistance	
	I _{hold} (A)	I _{trip} (A)	V _{max} (Vdc)	I _{max} (A)	P _{d typ} (W)	Current (A)	Time (Sec.)	$R_{min} \ (\Omega)$	R_{1max} (Ω)
SMD1206P016TF	0.16	0.37	30	100	0.60	1.00	0.30	1.200	4.500

Note: Ihold = Hold current: maximum current device will pass without tripping in 23°C still air.

I trip = Trip current: minimum current at which the device will trip in 23 °C still air.

V_{max} = Maximum voltage device can withstand without damage at rated current (I_{max})

I_{max} = Maximum fault current device can withstand without damage at rated voltage (V_{max})

P_{d typ} = Typical power dissipated from device when in the tripped state at 23 °C still air.

R_{min} = Minimum resistance of device in initial (un-soldered) state.

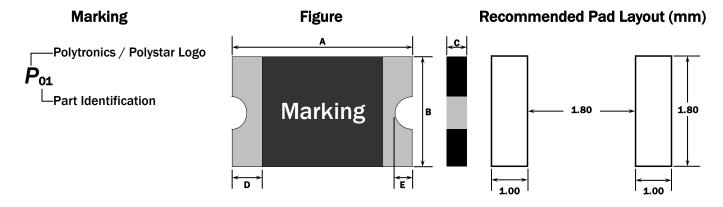
R_{1max} = Maximum resistance of device at 23 °C measured one hour after tripping or reflow soldering of 260 °C for 20 sec.

- *Value specified were determined using the PWB with 0.030"*1.5oz copper traces.
- *Customer should verify the device performance in their specified conditions.

Caution: Operation beyond the specified rating may result in damage and possible arcing and flame.

Recognitions:





Note: Polystar is Polytronics's manufacturing site in China. The Polystar ID marking shall appear on smallest package.

PHYSICAL DIMENSIONS (mm)

Part Number	Α		В		С		D		E	
	Min.	Max.								
SMD1206P016TF	3.00	3.40	1.50	1.80	0.65	1.45	0.25	0.75	0.05	0.45

Specifications are subject to change without notice.